

For capacitive load, derate current by 20%

Type Number	S4A	S4B	S4D	S4G	S4J	S4K	S4M	Units
Maximum Recurrent Peak Reverse Voltage	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current $@T_L = 75^{\circ}C$	43.0							А
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	100							А
Maximum Instantaneous Forward Voltage @ 4.0A	1.15							V
Maximum DC Reverse Current @ T <sub>A</sub> =25°C	10.0							uA
at Rated DC Blocking Voltage @ T <sub>A</sub> =125 $^{\circ}$ C	250							uA
Typical Thermal Resistance (Note 3) RθJL RθJA	13							°C <b>/W</b>
				47				
Maximum Reverse Recovery Time (Note 1)	2.5							uS
Typical Junction Capacitance (Note 2)	60							pF
Operating Temperature Range T <sub>J</sub>	-55 to +150							Ĉ
Storage Temperature Range TSTG	-55 to +150							°C

Notes: 1. Reverse Recovery Test Conditions: I<sub>F</sub>=0.5A, I<sub>R</sub>=1.0A, I<sub>RR</sub>=0.25A

2. Measured at 1 MHz and Applied  $V_R$ =4.0 Volts

3. Measured on P.C. Board with 0.3 x 0.3" (8x 8mm) Copper Pad Areas.



## RATINGS AND CHARACTERISTIC CURVES (S4A THRU S4M) FIG.1- MAXIMUM FORWARD CURRENT DERATING FIG.2- MAXIMUM NON-REPETITIVE FORWARD CURVE SURGE CURRENT 200 4.0 PEAK FORWARD SURGE CURRENT. (A) AVERAGE FORWARD CURRENT. (A) 3.5 100 3.0 2.5 50 2.0 1.5 RESISTIVE OR INDUCTIVE LOAD P. C. BOARD MOUNTED ON 8.0mm<sup>2</sup> 8.3ms Single Half Sine Wave JEDEC Method 1.0 PAD AREAS Tj=Tj max 0.5 L 50 1 1 1 10 60 100 110 70 80 90 120 130 140 150 5 10 50 100 LEAD TEMPERATURE. (°C) NUMBER OF CYCLES AT 60Hz FIG.3- TYPICAL FORWARD CHARACTERISTICS FIG.4- TYPICAL REVERSE CHARACTERISTICS 100 100 30 INSTANTANEOUS FORWARD CURRENT. (A) INSMANAANAENERSHAREREREGEURARERAFINT.A/#A) Tj=125°C 10 10 3.0 1.0 0.3 1.0 Tj=25°C 0.1 0.03 . Ti=25⁰C PULSE WIDTH-300µS 2% DUTY CYCLE 0.01 .10 0.6 0.7 .8 .9 1.0 1.2 1.4 1.6 0 80 100 120 140 20 40 60 FORWARD VOLTAGE. (V) PERCENT OF RATED PEAK REVERSE VOLTAGE. (%) FIG.5- TYPICAL JUNCTION CAPACITANCE 100 ++ JUNCTION CAPACITANCE.(pF) 50 Tj=25°C f=1.0MHz Vsig=50mVp-p 10 $\overline{}$ 5 100 5 10 50 1 REVERSE VOLTAGE. (V)